

**WNSC201200W** 

### Silicon Carbide Diode

Rev.01 - 22 April 2019

#### **Product data sheet**

### **1. General description**

Silicon Carbide Schottky diode in a TO247-2L plastic package, designed for high frequency switched-mode power supplies.



### 2. Features and benefits

- Highly stable switching performance
- High forward surge capability I<sub>FSM</sub>
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- High junction operating temperature capability (T<sub>j(max)</sub> = 175 °C)

### **3. Applications**

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
		Conditions		V C	liues		
Absolute	maximum rating						
$V_{\text{RRM}}$	repetitive peak reverse voltage		1200				
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 131 °C; Fig. 1; Fig. 2; Fig. 3; Fig. 4	20				A
T <sub>j</sub>	junction temperature			175			
Symbol	Parameter	Conditions	Min Typ Max				Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.4	1.6	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.85	2.3	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>		-	2	2.6	V
Dynamic	characteristics	·			,		
Q <sub>r</sub>	recovered charge	$I_F = 20 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 8$		-	52	-	nC

# **5. Pinning information**

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		K — A 001aaa020
2	А	anode		001888020
mb	К	mounting base; connected to cathode	С О О П	

# 6. Ordering information

Table 3. Ordering information												
Type number	Package name	Orderable part number	Packing method	Small packing quantity		Package issue date						
WNSC201200W	TO247-2L	WNSC201200WQ	Tube	30	TO247L-2L	28-Aug-2018						

# 7. Marking

Table 4. Marking codes								
	Type number	Marking codes						
	WNSC201200W	WNSC201200W						

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit	
$V_{\text{RRM}}$	repetitive peak reverse voltage		1200	V	
V <sub>RWM</sub>	crest working reverse voltage		1200	V	
V <sub>R</sub>	reverse voltage	DC	1200	V	
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 131 °C; Fig. 1; Fig. 2; Fig. 3; Fig. 4	20	A	
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 131 °C; square-wave pulse	40	A	
I <sub>FSM</sub>	non-repetitive peak				
	forward current	$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; sine-wave pulse	1440	А	
T <sub>stg</sub>	storage temperature		-55 to 175	°C	
Tj	junction temperature		175	°C	

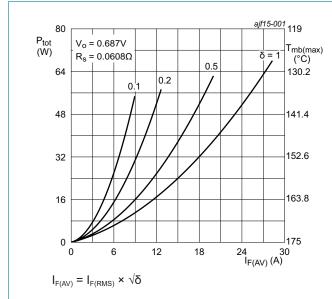
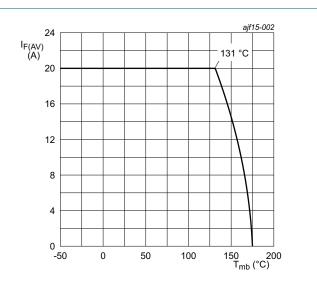
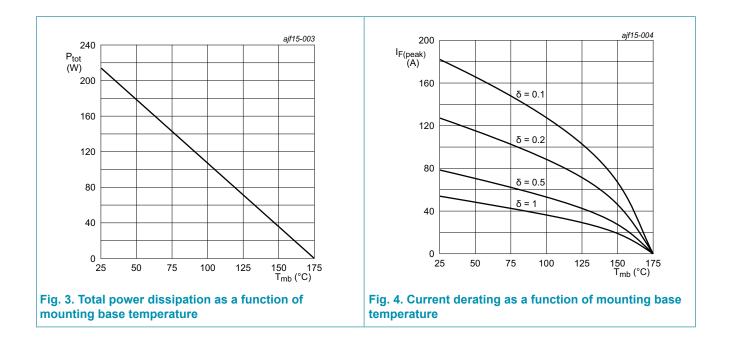


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; typical values



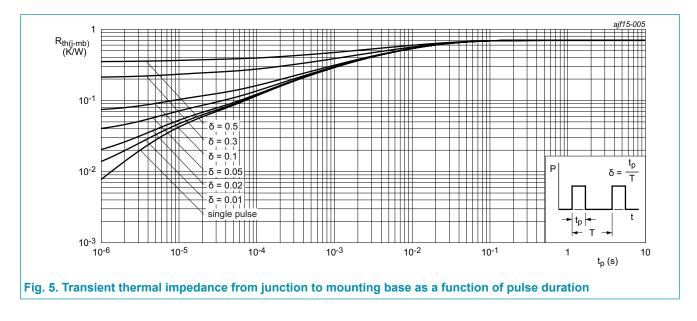


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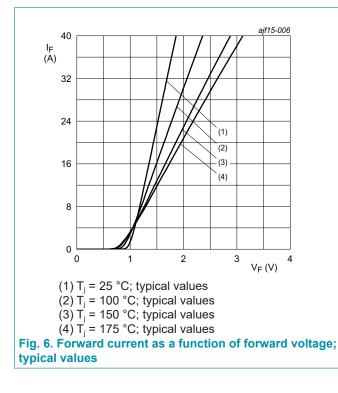
# 9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	0.7	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W



### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	aracteristics				indix	
V <sub>F</sub>	forward current	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.4	1.6	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	1.85	2.3	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>	-	2	2.6	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	200	μA
		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 175 °C; <u>Fig. 7</u>	-	-	1	mA
Dynamic	characteristics	· · · · · ·				
Q <sub>r</sub>	recovered charge	I <sub>F</sub> = 20 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	52	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	1020	-	pF
		f = 1 MHz; V <sub>R</sub> = 400 V; T <sub>j</sub> = 25 °C	-	96	-	pF
		f = 1 MHz; V <sub>R</sub> = 800 V; T <sub>j</sub> = 25 °C	-	82	-	pF



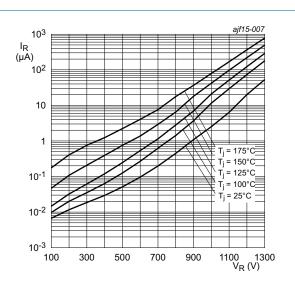
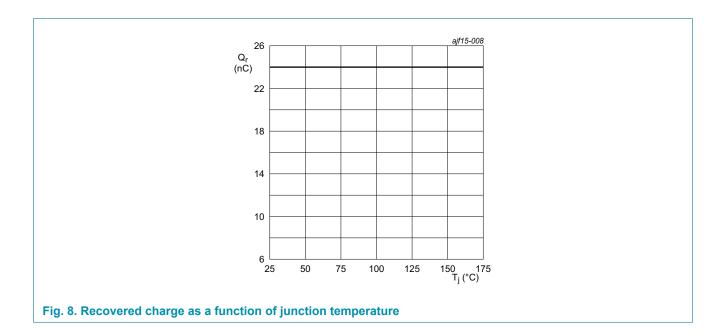


Fig. 7. Reverse leakage current as a function of reverse voltage; typical value

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# **11. Package outline**

	-				e		- b1	E2	Q			- - C								D2
UNIT	A	A	Ъ	<b>b</b> 1	C	D	D1	$\mathbf{D}_2$	Е	E <sub>1</sub>	E <sub>2</sub>	E3	е	L	L	P <sub>2</sub>	p	Q	q	ø

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# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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